

KSD5041

AF Output Amplifier for Electronic Flash Unit

- Low Collector-Emitter Saturation Voltage
- High Performance at Low Supply Voltage



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	40	V
V _{CEO}	Collector-Emitter Voltage	20	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current	5	A
P _C	Collector Power Dissipation	0.75	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =1mA, I _B =0	20			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _C =10μA, I _C =0	7			V
I _{CBO}	Collector Cut-off Current	V _{CB} =10V, I _E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} =7V, I_{C} =0			0.1	μΑ
h _{FE1}	DC Current Gain	V _{CE} =2V, I _C =0.5A	180		600	
h _{FE2}		V _{CE} =2V, I _C =2A	150			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =3A, I _B =0.1A			1	V
f _T	Current Gain Bandwidth Product	V _{CE} =6V, I _C =50mA		150		MHz
C _{ob}	Output Capacitance	V _{CB} =20V, I _E =0, f=1MHz			50	pF

h_{FE} Classification

Classification	Р	Q	R
h _{FE}	180 ~ 270	230 ~ 380	340 ~ 600

Typical Characteristics

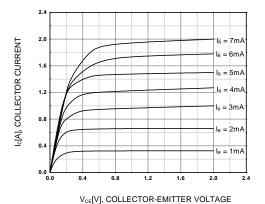


Figure 1. Static Characteristic

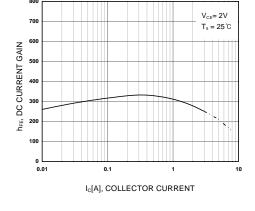


Figure 2. DC current Gain

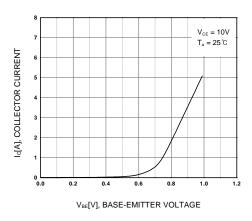


Figure 3. Base-Emitter Saturation Voltage

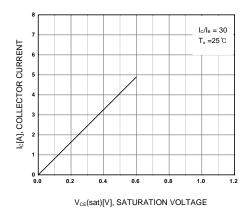


Figure 4. Collector-Emitter Saturation Voltage

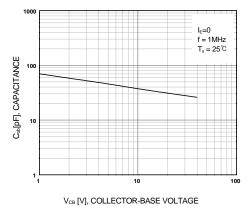


Figure 5. Collector Output Capacitance

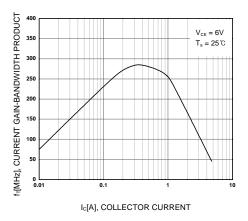


Figure 6. Current Gain Bandwidth Product

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Typical Characteristics (Continued)

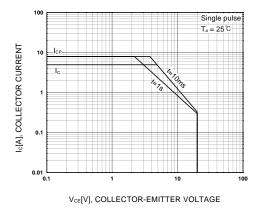


Figure 7. Safe Operating Area

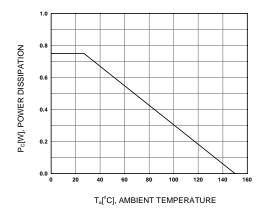
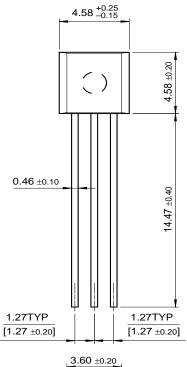
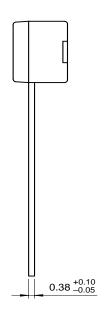


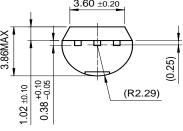
Figure 8. Power Derating

Package Demensions

TO-92







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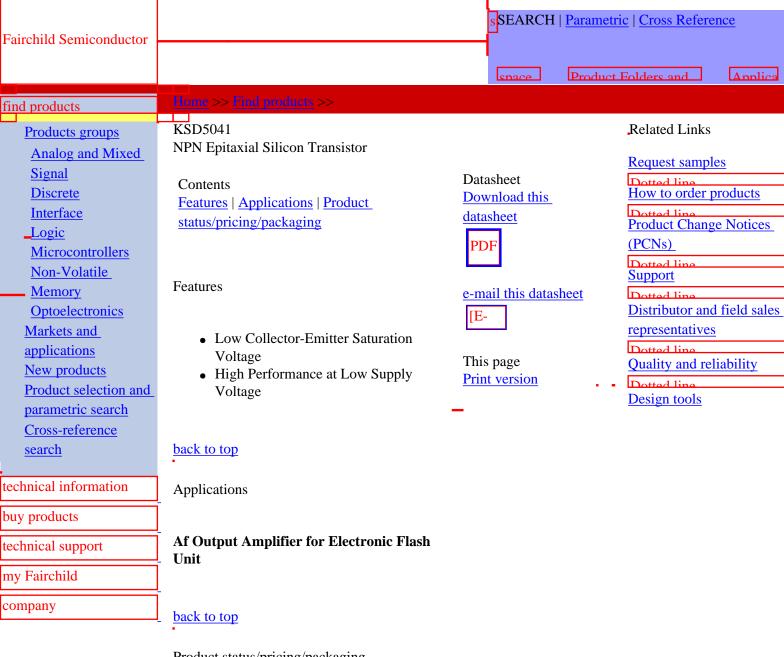
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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSD5041PBU	Full Production	\$0.073	<u>TO-92</u>	3	BULK
KSD5041QTA	Full Production	\$0.073	<u>TO-92</u>	3	TAPE REEL
KSD5041RBU	Full Production	\$0.073	<u>TO-92</u>	3	BULK
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KSD5041RTA	Full Production	\$0.073	<u>TO-92</u>	3	TAPE REEL

^{* 1,000} piece Budgetary Pricing

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